

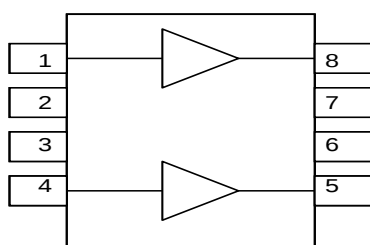
Product Overview

The QPB7464 is a GaAs pHEMT 75-ohm RF differential amplifier with an operating bandwidth from 47 MHz to 1.218 GHz. Featuring 12 dB of flat gain for use in Broadband DOCSIS 3.1 applications. This MMIC uses a 5-volt supply and is offered in an 8-pin SOIC.



SOIC-8 Package

Functional Block Diagram



Top View

Key Features

- 47 – 1218 MHz Bandwidth
- 75 Ω Impedance
- Meets DOCSIS 3.1 Output Requirements
- +5 V Supply Voltage
- 240 mA Current Consumption
- SOIC – 8 package
- +37 dBm OIP3
- +23.6 dBm OP1dB
- 12 dB Gain

Applications

- DOCSIS 3.1 systems
- HFC Optical Nodes and Amplifiers
- MDU Output
- Cable TV Network Equipment

Ordering Information

Part Number	Description
QPB7464SB	Sample bag with 5 pieces
QPB7464SR	7" Reel with 100 pieces
QPB7464TR13	13" Reel with 2500 pieces
QPB7464PCK401	47 – 1218 MHz PCBA

Absolute Maximum Ratings

Parameter	Rating
Supply Voltage (V_{DD})	+10 V
Supply Current (I_{DD})	300 mA
Maximum Input Level (single tone)	+12 dBm
Operating Temperature Range	-40 to +100 °C
Storage Temperature Range	-65 to +165 °C
Maximum Junction Temperature	+150 °C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating condition to the device may reduce device reliability.

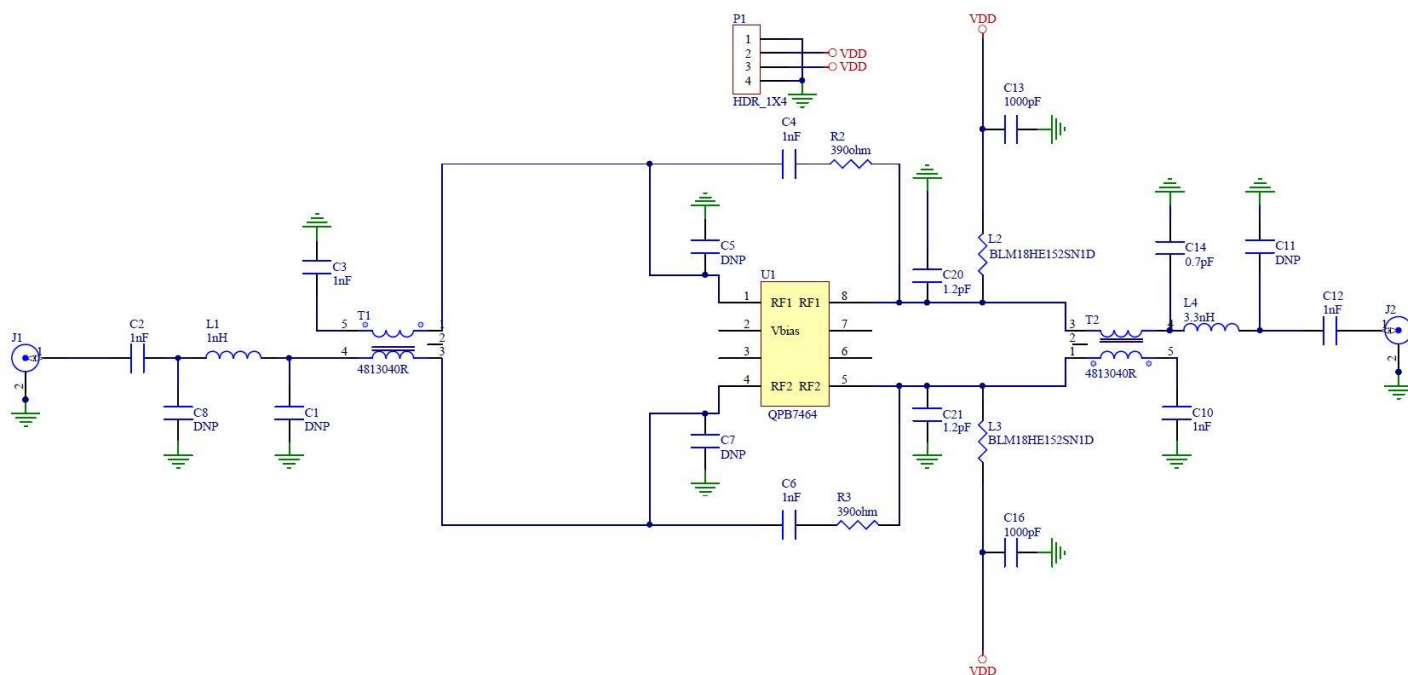
Electrical Specifications

Parameter	Condition	Min	Typ	Max	Unit
Supply Voltage (V_{DD})			5		V
Supply Current (I_{DD})			240		mA
Frequency Range		47		1218	MHz
Gain	1218 MHz		12.3		dB
Gain Flatness	Max. deviation from line using least squares fit from 47 to 1218 MHz		± 0.1 dB		dB
Gain Slope	Gain (1218 MHz) – Gain (50 MHz)		0.2		dB
Reverse Isolation			17.5		dB
Input Return Loss			17.2		dB
Output Return Loss			16.1		dB
Noise Figure	1218 MHz		3.8		dB
OIP2	Low band: 200 MHz, 30 MHz spacing, 6 dBm/tone		77.3		dBm
	High band: 1100 MHz, 30 MHz spacing, 6 dBm/tone		53.6		dBm
OIP3	Low band: 200 MHz, 6 MHz spacing, 6 dBm/tone		40.1		dBm
	High band: 1100 MHz, 6 MHz spacing, 6 dBm/tone		39.3		dBm
Output P1dB	1218 MHz		23.6		dBm
Thermal Resistance	Θ_{JC} (Junction to Case)		14		°C/W

Notes:

1. Typical performance at these conditions: Temp = +25 °C, V_{DD} = +5 V, 75 Ω system, Full band unless otherwise noted

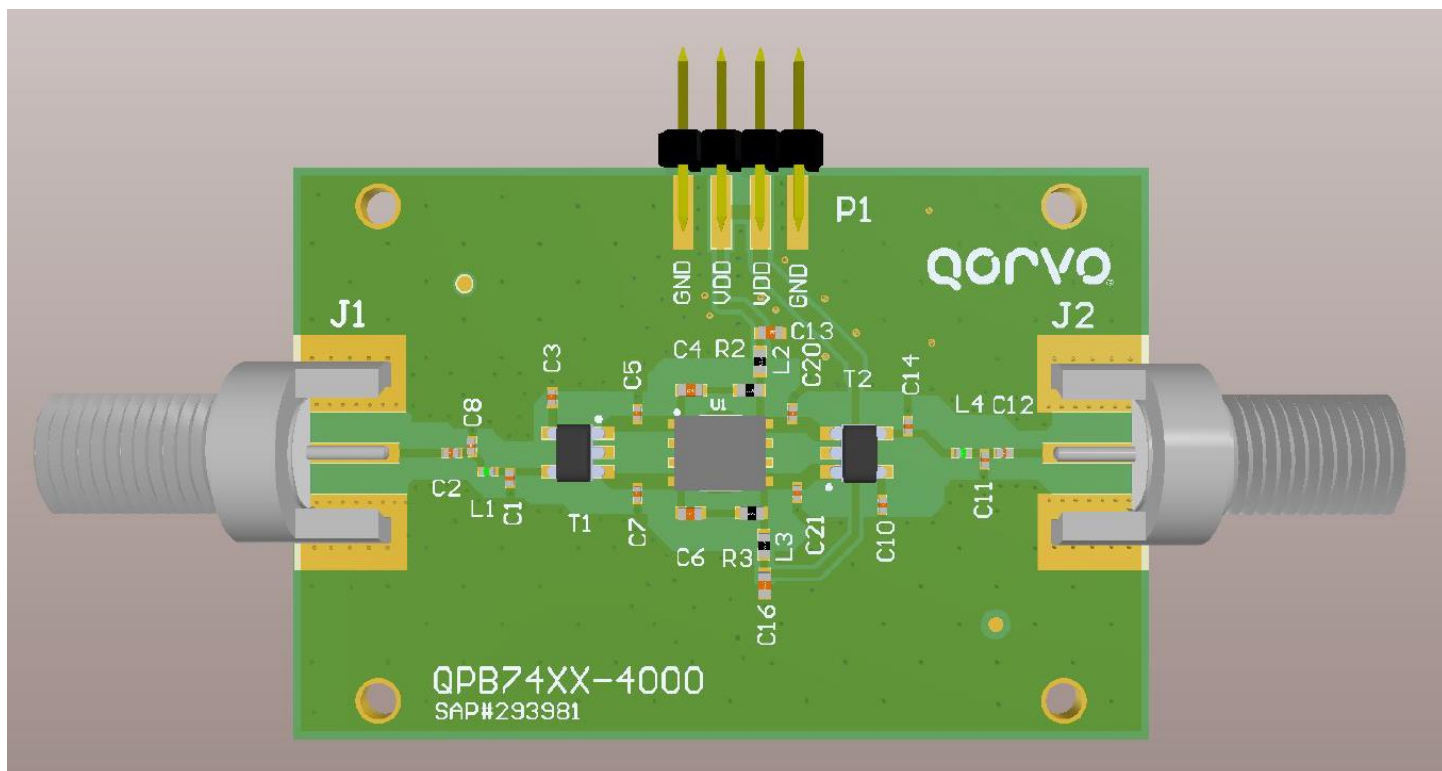
Evaluation Board Schematic



**QPB7464****CATV 75 Ω pHEMT Dual RF Amplifier****Evaluation Board Bill of Materials**

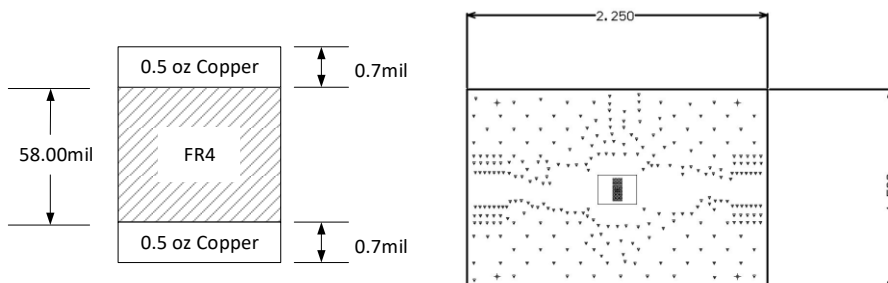
Ref Designator	Description	Manufacturer	P/N
U1	QPB7464 pHEMT Dual RF Amplifier	Qorvo	QPB7464
PCB	QPB74XX-4000	Viasystems Technologies Corp LLC	
C2, C3, C10, C12	CAP, 1000 pF, 5 %, 50 V, C0G, 0402	Murata Electronics	GRM1555C1H102JA01D
C4, C6, C13, C16	CAP, 1000 pF, 50 V, 10%, 0603	AVX Asia Ltd.	06035C102KAT2A
C14	CAP, 0.7 pF, +/-0.1 pF, 16 V, HI-Q, 0402	Taiyo Uden PTE Ltd.	RV EVK105CH0R7BW-F
C20, C21	CAP, 1.2 pF, +/-0.1 pF, 200 V, Hi-Q, 0402	ATC	600L1R2BT200T
J1, J2	CONN, F FEM EDGE MOUNT, 75 Ω , 0.068"	Millimeter Wave Technologies, LLC	MW-846-C-DD-75
L1	IND, 1 nH, 5 %, W/W, 0402	Coilcraft, Inc.	0402CS-1N0XJLW
L2, L3	FER, BEAD, 1500 Ω , 500 mA, 0603	Murata Electronics	BLM18HE152SN1D
L4	IND, 3.3 nH, 2 %, 1.7 A, W/W, 0402	Coilcraft, Inc.	0402HP-3N3XGLW
P1	CONN, HDR, ST, FRCTN LOCK, 4-PIN	Molex	22-23-2041
R2, R3	RES, 390 Ω , 5 %, 1/16W, 0603	Panasonic	ERJ-3GEYJ391
T1, T2	Balun	Minntronix	4813040R
C1, C5, C7, C8, C11	Not Populated		

Evaluation Board Assembly Drawing

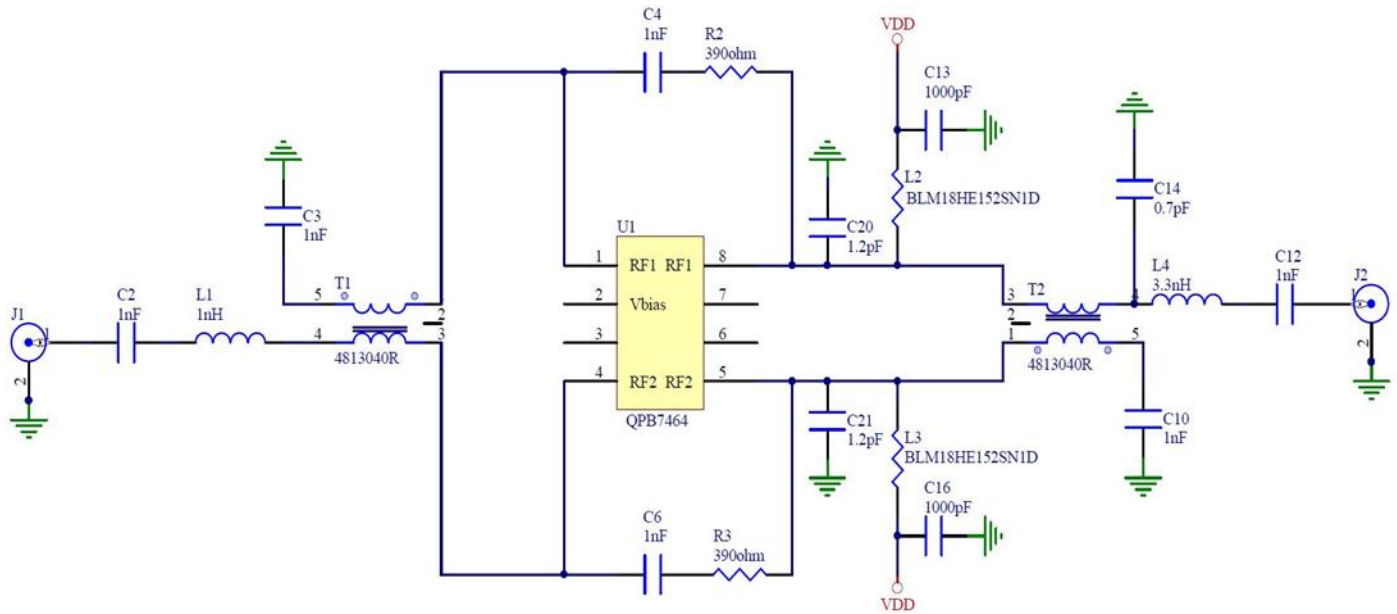


EVB PCB Material and Stack-up

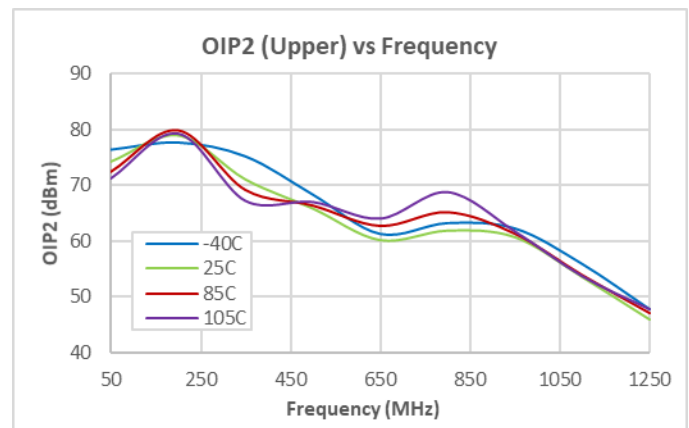
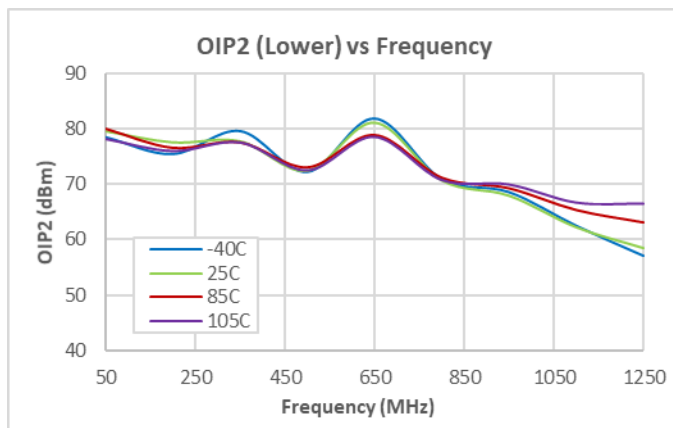
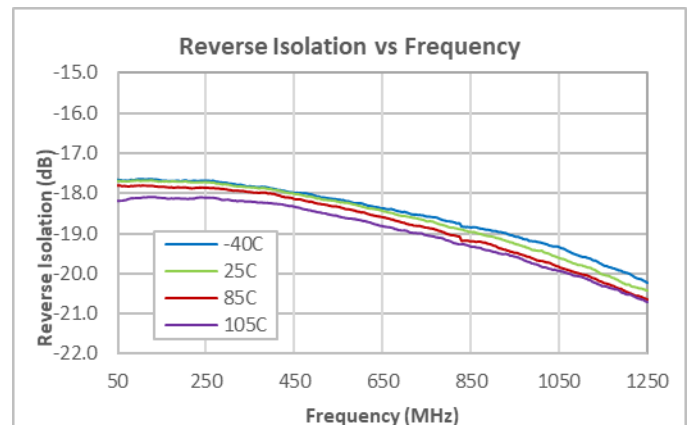
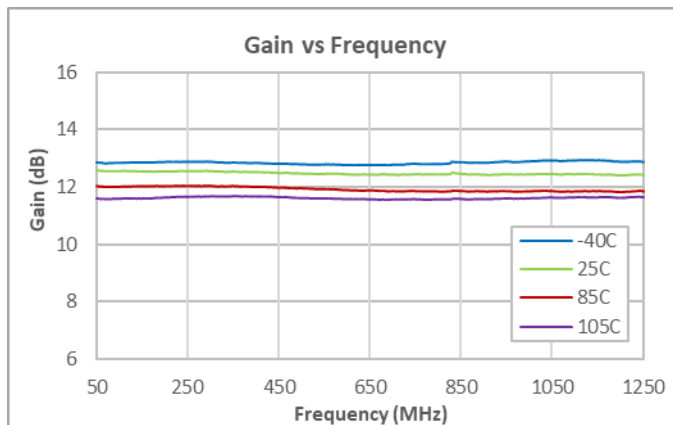
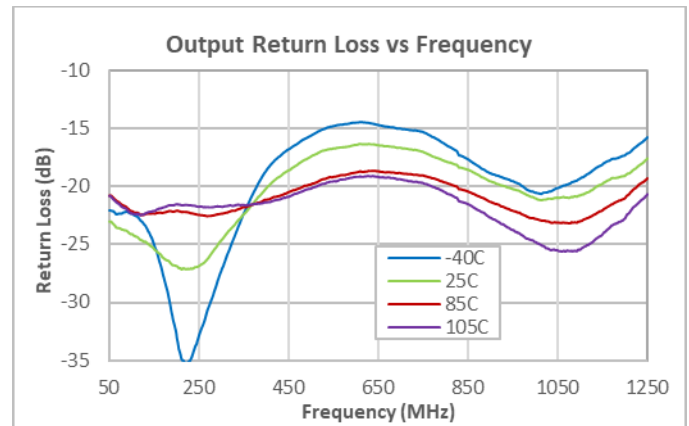
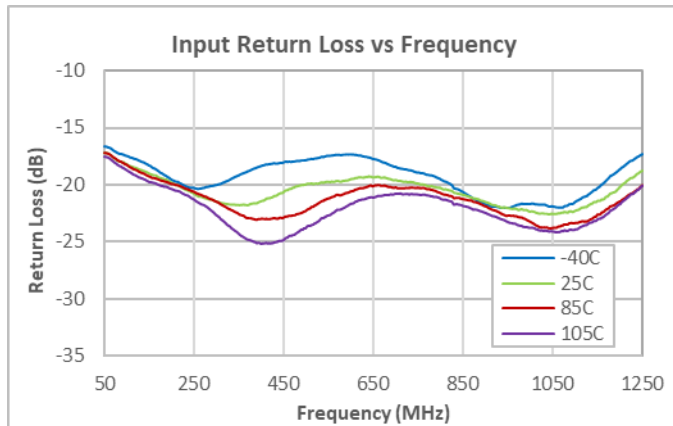
Board Material: 0.058" FR4, $\epsilon_r=4.2$
 Plating: 0.5oz Copper
 Board Dimension: 2.25" x 1.5"



Typical Application Schematic



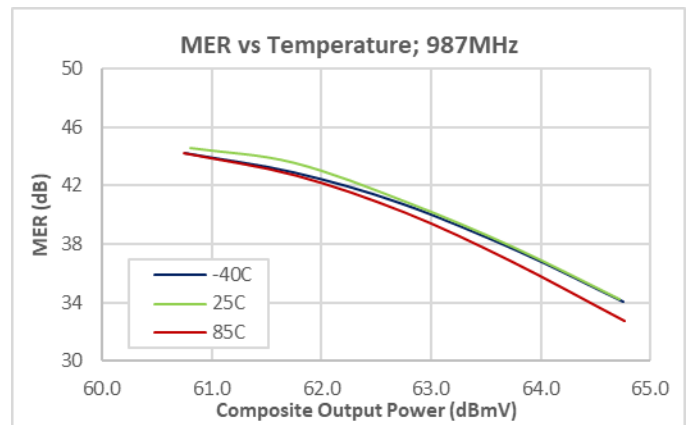
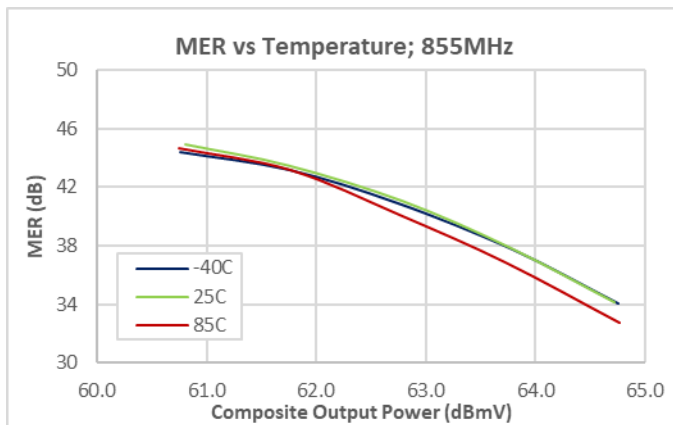
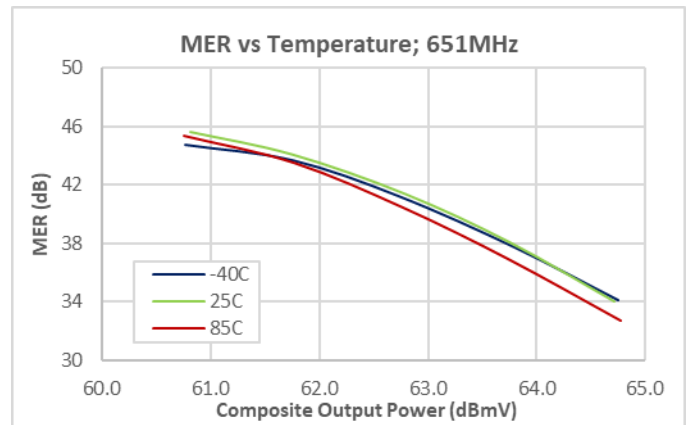
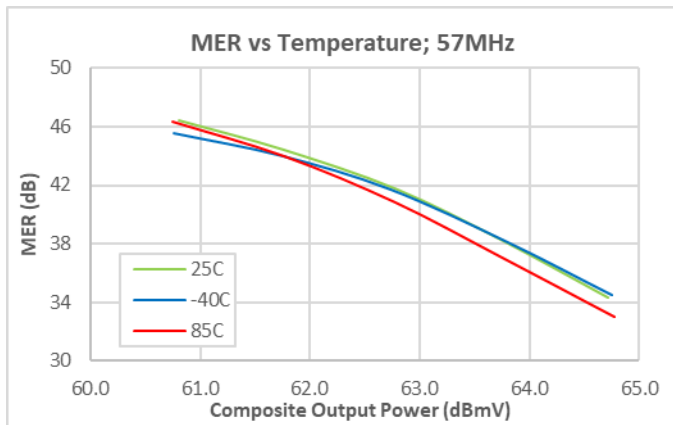
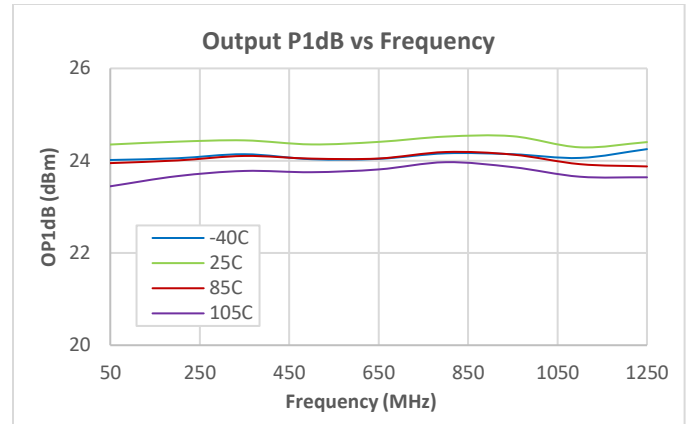
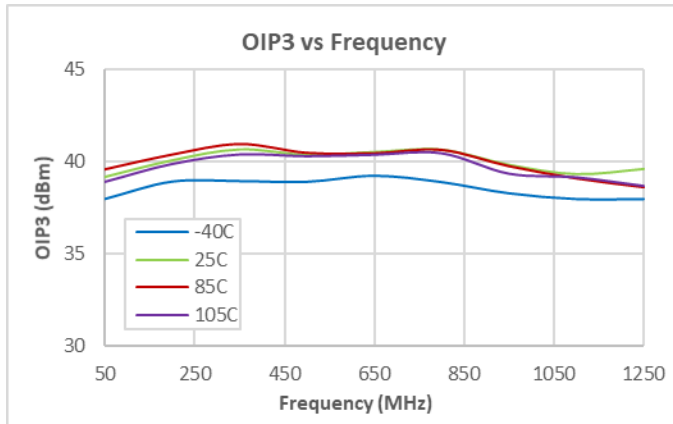
Performance Data



Test Conditions:

1. Test conditions unless otherwise noted: $V_{DD} = +5V$, $Z_0 = 75\Omega$
2. OIP2: +6 dBm per Output Tone.

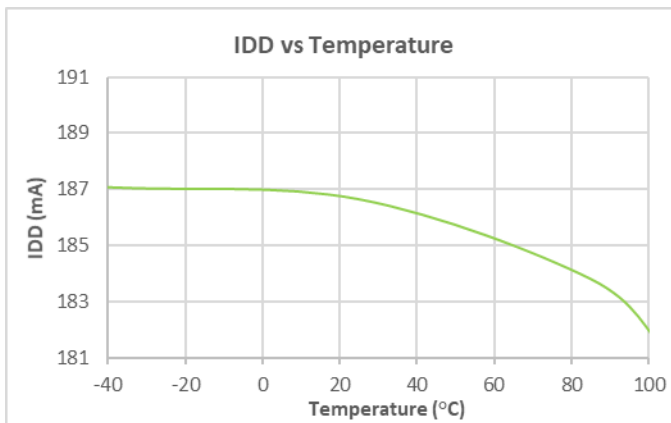
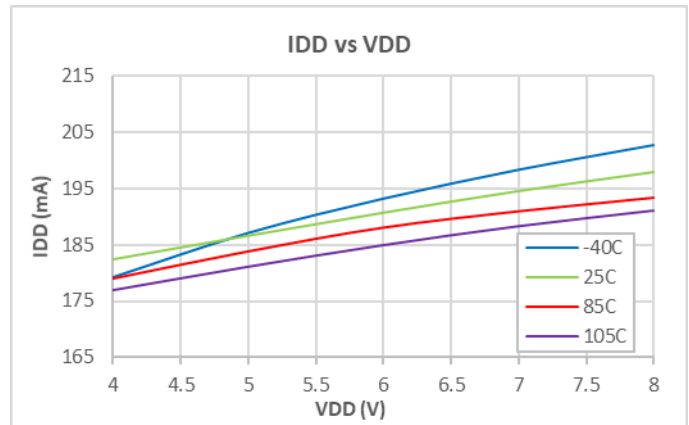
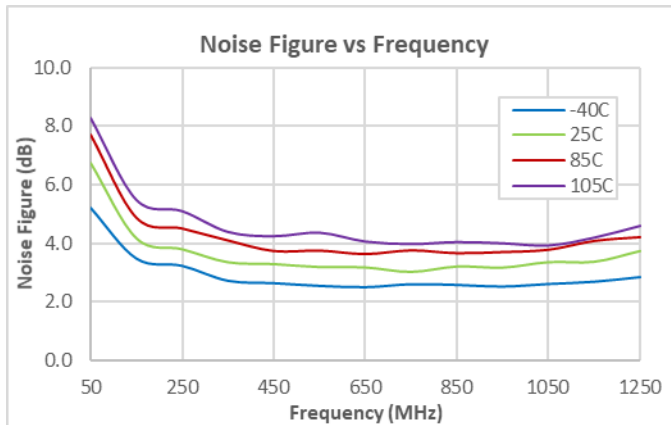
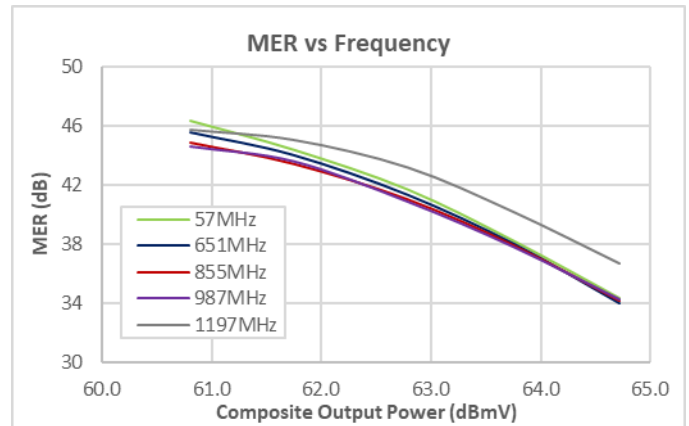
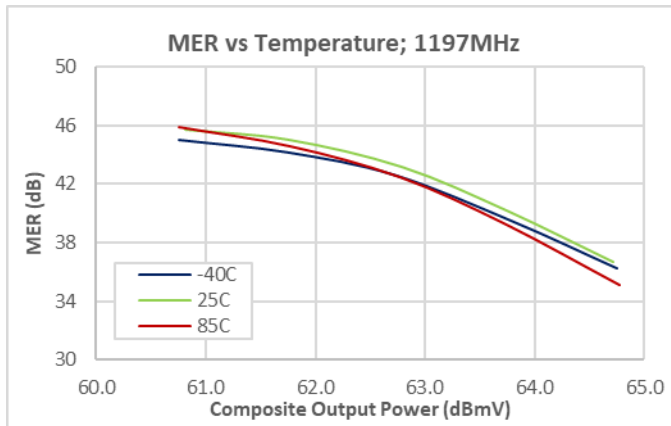
Performance Data (cont'd)



Test Conditions:

1. Test conditions unless otherwise noted: $V_{DD} = +5V$, $Z_0 = 75\Omega$
2. OIP3: +6 dBm per Output Tone.
3. MER: 190 QAM256 Channels Flat Tilt, 57 – 1215 MHz, ITU-T J.83, Annex B

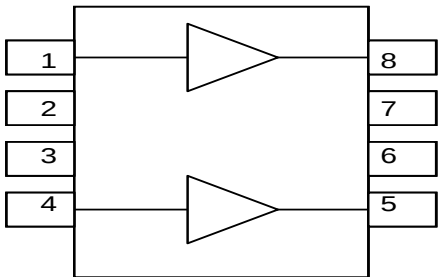
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Test Conditions:

1. Test conditions unless otherwise noted: $V_{DD} = +5V$, $Z_0 = 75\Omega$
2. MER: 190 QAM256 Channels Flat Tilt, 57 – 1215 MHz, ITU-T J.83, Annex B

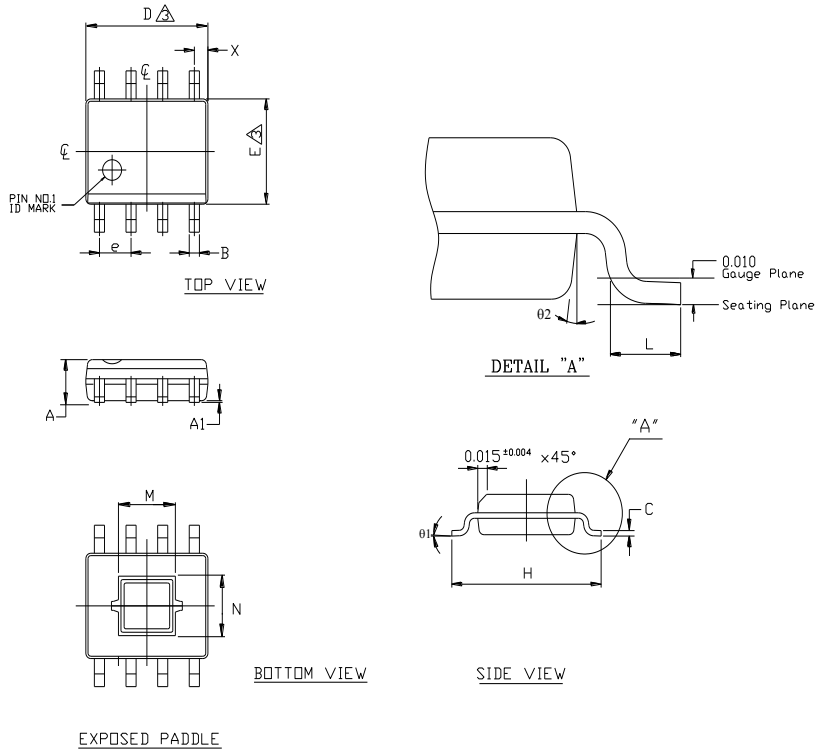
Pin Configuration and Description



Top View

Pin Number	Label	Description
1	RF _{INA}	RF Input A. DC blocking capacitor required.
2	NC	Not Connected
3	NC	Not Connected
4	RF _{INB}	RF Input B. DC blocking capacitor required.
5	RF _{OUTB} / V _{DD}	RF Output B.
6	NC	Not Connected
7	NC	Not Connected
8	RF _{OUTA} / V _{DD}	RF Output A.
Backside Pad	RF/DC GND	Ground Slug

Package Outline

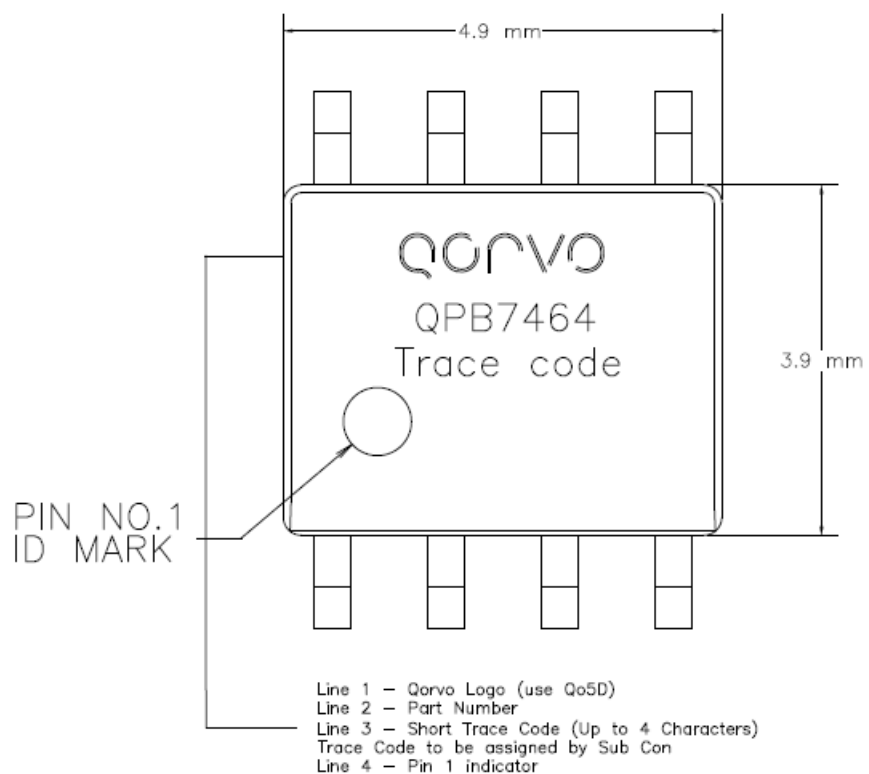


SYMBOL	8 SOIC	
	MIN	MAX
A	0.054	0.068
A1	0.001	0.004
B	0.014	0.019
D	0.189	0.197
E	0.150	0.157
H	0.228	0.244
M	0.072	0.097
N	0.067	0.092
e	0.050	BSC
C	0.0070	0.0010
L	0.016	0.050
X	0.0215	REF
$\theta 1$	0°	8°
$\theta 2$	7°	BSC

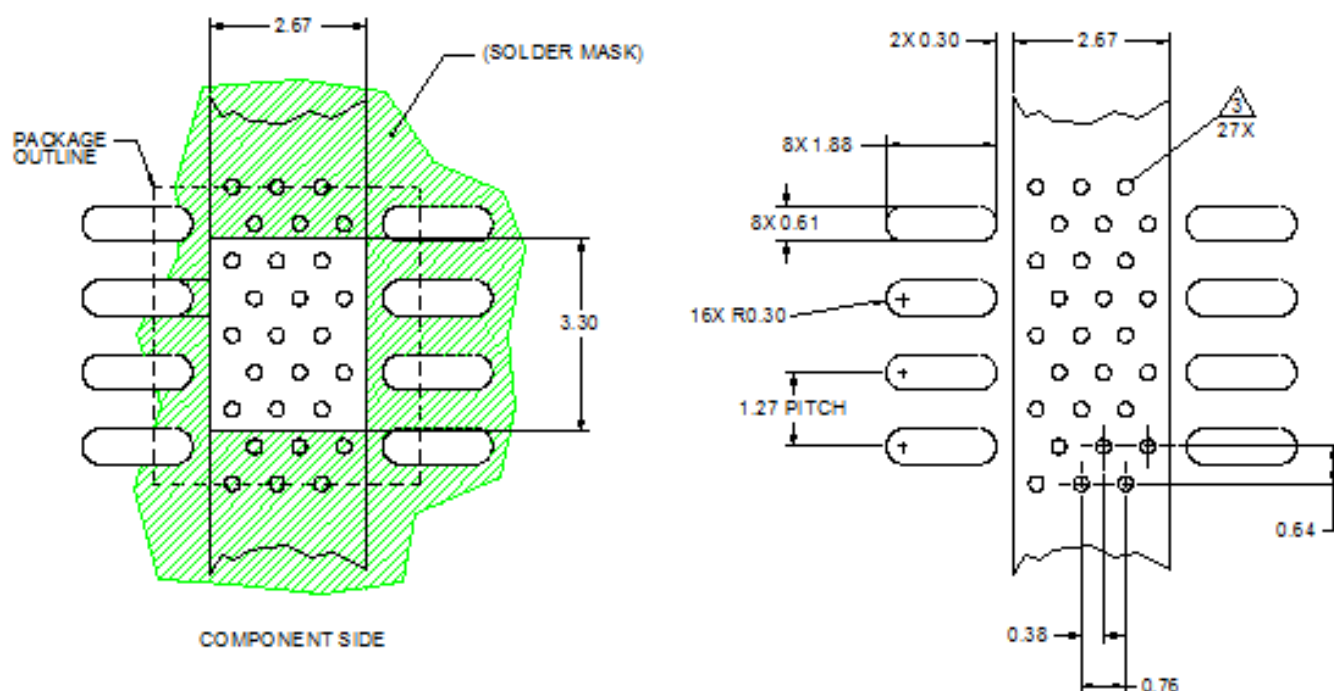
NOTE :

1. All dimension are in inch
2. Top package surface to be NiPdAu plating
3. Bottom package surface to be NiPdAu plating
4. Dimension are exclusive of mold flash and gate burr
5. Foot length measurement is based on the gauge plane method

Package Marking



Recommended Mounting Pattern



Notes:

- All dimensions are in millimeters. Angles are in degrees.
- Use 0.5 oz. copper minimum for top and bottom layer metal.
- Vias are required under the backside paddle of this device for proper RF/DC grounding and thermal dissipation.
- We recommend a 0.35 mm (#80/.0135") diameter bit for drilling via holes and a final plated thru diameter of 0.25 mm (0.010")
- Ensure good package backside paddle solder attach for reliable operation and best electrical performance.

Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A (500V)	ESDA / JEDEC JS-001-2014
ESD – Charged Device Model (CDM)	Class C3 (1000V)	JEDEC JS-002-2014
MSL – Moisture Sensitivity Level	Level 3	IPC/JEDEC J-STD-020



Caution!
ESD-Sensitive Device

Solderability

Compatible with both lead-free (260 °C max. reflow temp.) and tin / lead (245 °C max. reflow temp.) soldering processes. Solder profiles available upon request.

Contact plating: NiPdAu

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- SVHC Free



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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Web: www.qorvo.com

Email: customer.support@qorvo.com

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